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Amplifier Transistors

NPN Silicon

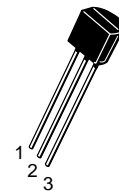
MAXIMUM RATINGS

Rating	Symbol	BC546	BC547	BC548	Unit
Collector–Emitter Voltage	V_{CEO}	65	45	30	Vdc
Collector–Base Voltage	V_{CBO}	80	50	30	Vdc
Emitter–Base Voltage	V_{EBO}	6.0			Vdc
Collector Current — Continuous	I_C	100			mAdc
Total Device Dissipation @ $T_A = 25^\circ\text{C}$ Derate above 25°C	P_D	625			mW
		5.0			mW/ $^\circ\text{C}$
Total Device Dissipation @ $T_C = 25^\circ\text{C}$ Derate above 25°C	P_D	1.5			Watt
		12			mW/ $^\circ\text{C}$
Operating and Storage Junction Temperature Range	T_J, T_{stg}	–55 to +150			$^\circ\text{C}$

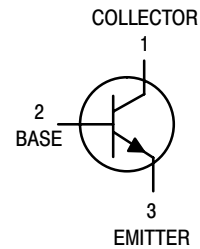
THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	200	$^\circ\text{C}/\text{W}$
Thermal Resistance, Junction to Case	$R_{\theta JC}$	83.3	$^\circ\text{C}/\text{W}$

BC546
BC546B
BC547A
BC547B
BC547C
BC548B
BC548C



CASE 29–04, STYLE 17
TO–92 (TO–226AA)



ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ unless otherwise noted)

Characteristic	Symbol	Min	Typ	Max	Unit
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OFF CHARACTERISTICS

Collector–Emitter Breakdown Voltage ($I_C = 1.0\text{ mA}, I_B = 0$)	BC546	$V_{(BR)CEO}$	65	—	—	V
	BC547		45	—	—	
	BC548		30	—	—	
Collector–Base Breakdown Voltage ($I_C = 100\ \mu\text{Adc}$)	BC546	$V_{(BR)CBO}$	80	—	—	V
	BC547		50	—	—	
	BC548		30	—	—	
Emitter–Base Breakdown Voltage ($I_E = 10\ \mu\text{A}, I_C = 0$)	BC546	$V_{(BR)EBO}$	6.0	—	—	V
	BC547		6.0	—	—	
	BC548		6.0	—	—	
Collector Cutoff Current ($V_{CE} = 70\text{ V}, V_{BE} = 0$) ($V_{CE} = 50\text{ V}, V_{BE} = 0$) ($V_{CE} = 35\text{ V}, V_{BE} = 0$) ($V_{CE} = 30\text{ V}, T_A = 125^\circ\text{C}$)	BC546	I_{CES}	—	0.2	15	nA
	BC547		—	0.2	15	
	BC548		—	0.2	15	
	BC546/547/548		—	—	4.0	μA
				—	—	

BC546 BC546B BC547A BC547B BC547C BC548B BC548C

ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ unless otherwise noted) (Continued)

Characteristic	Symbol	Min	Typ	Max	Unit
ON CHARACTERISTICS					
DC Current Gain ($I_C = 10\ \mu\text{A}$, $V_{CE} = 5.0\ \text{V}$)	BC547A BC546B/547B/548B BC548C	h_{FE}	— — —	90 150 270	—
($I_C = 2.0\ \text{mA}$, $V_{CE} = 5.0\ \text{V}$)	BC546 BC547 BC548 BC547A BC546B/547B/548B BC547C/BC548C		110 110 110 110 200 420	— — — 180 290 520	— 800 800 220 450 800
($I_C = 100\ \text{mA}$, $V_{CE} = 5.0\ \text{V}$)	BC547A/548A BC546B/547B/548B BC548C		— — —	120 180 300	— — —
Collector–Emitter Saturation Voltage ($I_C = 10\ \text{mA}$, $I_B = 0.5\ \text{mA}$) ($I_C = 100\ \text{mA}$, $I_B = 5.0\ \text{mA}$) ($I_C = 10\ \text{mA}$, $I_B = \text{See Note 1}$)		$V_{CE(sat)}$	— — —	0.09 0.2 0.3	0.25 0.6 0.6
Base–Emitter Saturation Voltage ($I_C = 10\ \text{mA}$, $I_B = 0.5\ \text{mA}$)		$V_{BE(sat)}$	—	0.7	—
Base–Emitter On Voltage ($I_C = 2.0\ \text{mA}$, $V_{CE} = 5.0\ \text{V}$) ($I_C = 10\ \text{mA}$, $V_{CE} = 5.0\ \text{V}$)		$V_{BE(on)}$	0.55 —	— —	0.7 0.77

SMALL–SIGNAL CHARACTERISTICS

Current–Gain — Bandwidth Product ($I_C = 10\ \text{mA}$, $V_{CE} = 5.0\ \text{V}$, $f = 100\ \text{MHz}$)	BC546 BC547 BC548	f_T	150 150 150	300 300 300	— — —	MHz
Output Capacitance ($V_{CB} = 10\ \text{V}$, $I_C = 0$, $f = 1.0\ \text{MHz}$)		C_{obo}	—	1.7	4.5	pF
Input Capacitance ($V_{EB} = 0.5\ \text{V}$, $I_C = 0$, $f = 1.0\ \text{MHz}$)		C_{ibo}	—	10	—	pF
Small–Signal Current Gain ($I_C = 2.0\ \text{mA}$, $V_{CE} = 5.0\ \text{V}$, $f = 1.0\ \text{kHz}$)	BC546 BC547/548 BC547A BC546B/547B/548B BC547C/548C	h_{fe}	125 125 125 240 450	— — 220 330 600	500 900 260 500 900	—
Noise Figure ($I_C = 0.2\ \text{mA}$, $V_{CE} = 5.0\ \text{V}$, $R_S = 2\ \text{k}\Omega$, $f = 1.0\ \text{kHz}$, $\Delta f = 200\ \text{Hz}$)	BC546 BC547 BC548	NF	— — —	2.0 2.0 2.0	10 10 10	dB

Note 1: I_B is value for which $I_C = 11\ \text{mA}$ at $V_{CE} = 1.0\ \text{V}$.

BC547/BC548

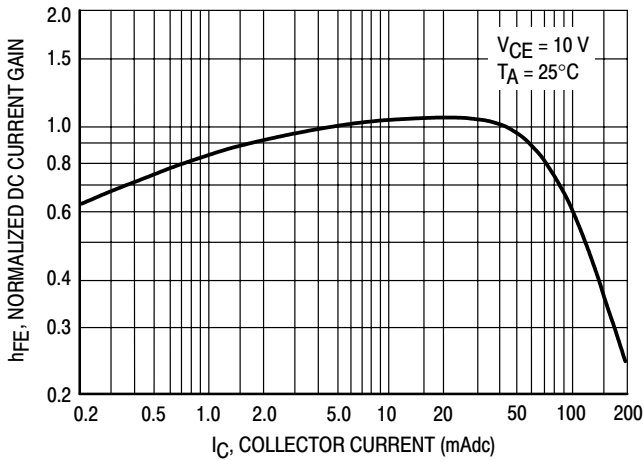


Figure 1. Normalized DC Current Gain

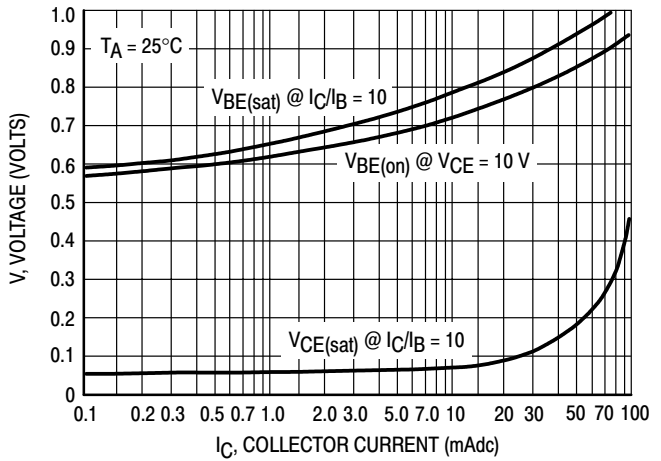


Figure 2. "Saturation" and "On" Voltages

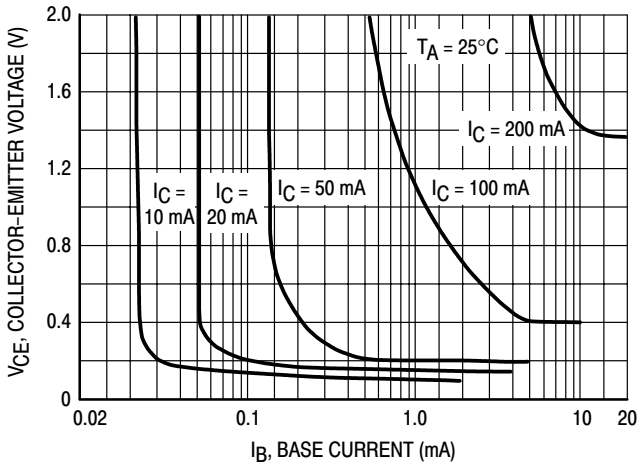


Figure 3. Collector Saturation Region

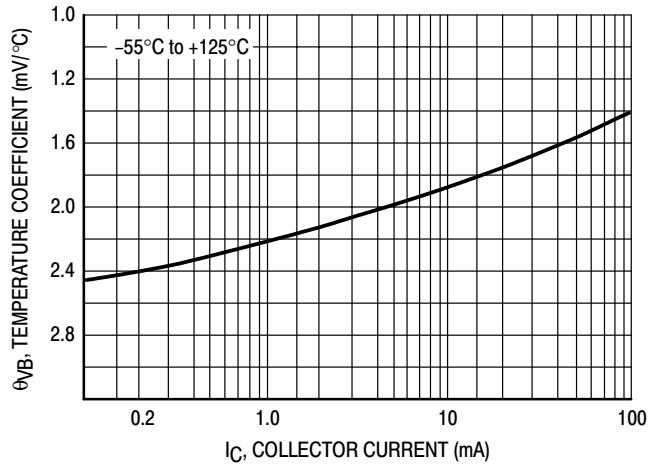


Figure 4. Base-Emitter Temperature Coefficient

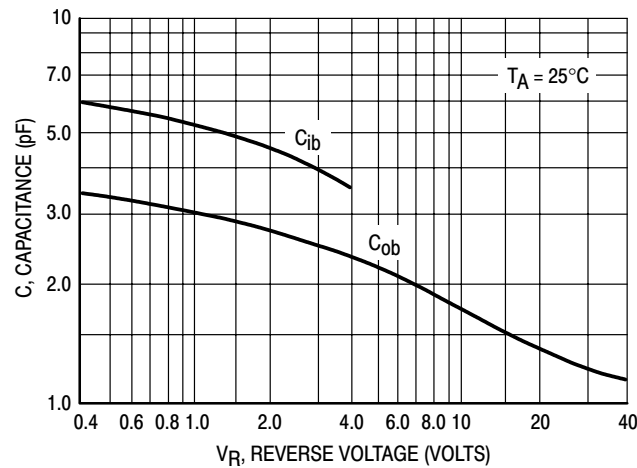


Figure 5. Capacitances

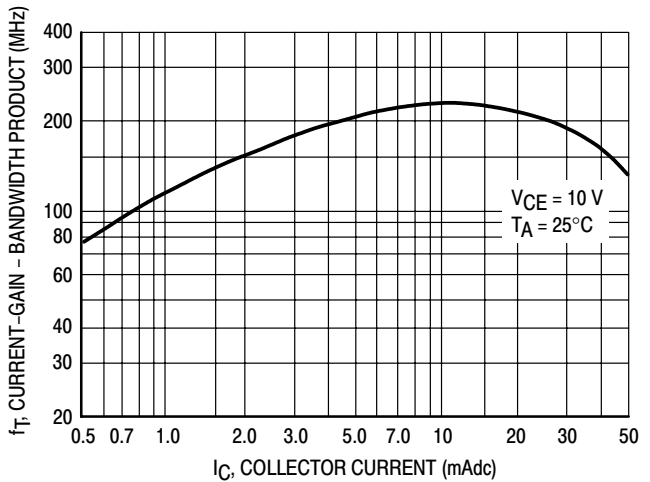


Figure 6. Current-Gain - Bandwidth Product

BC546

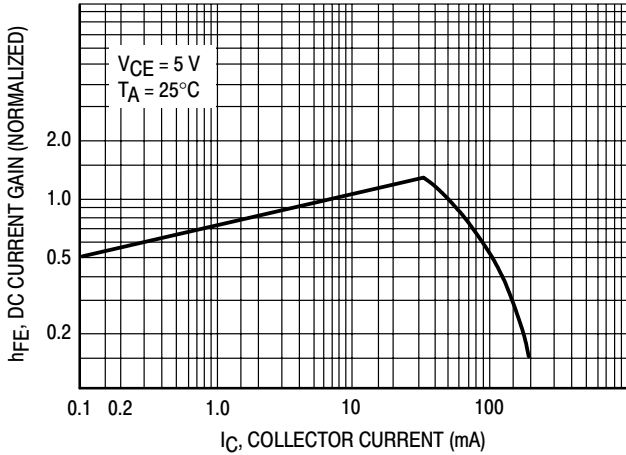


Figure 7. DC Current Gain

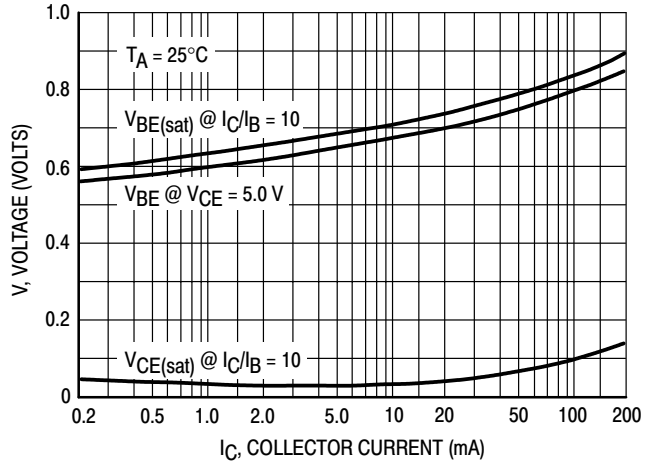


Figure 8. "On" Voltage

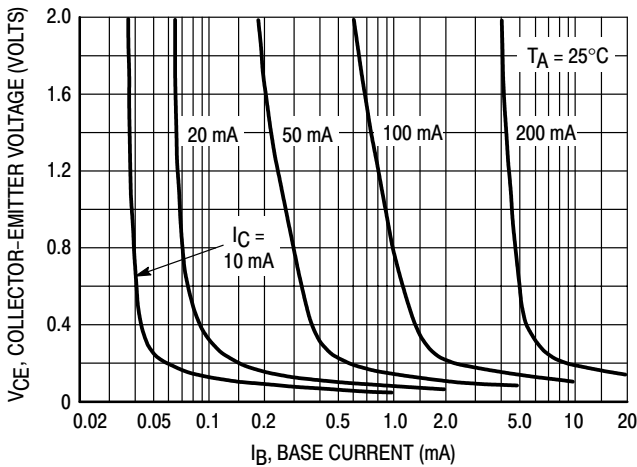


Figure 9. Collector Saturation Region

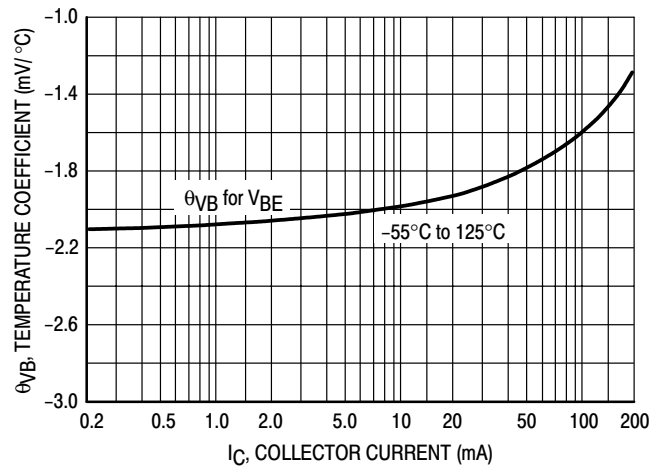


Figure 10. Base-Emitter Temperature Coefficient

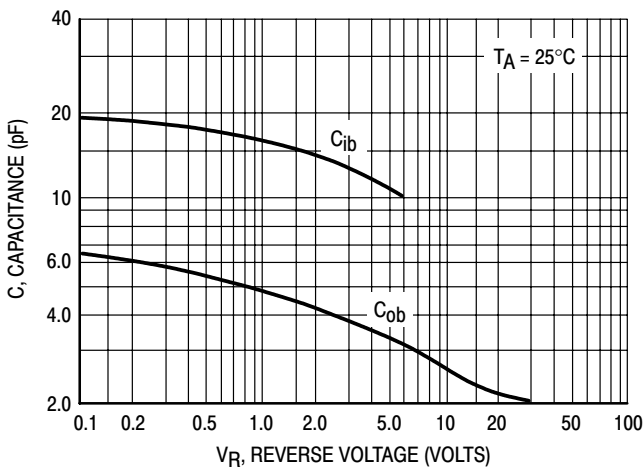


Figure 11. Capacitance

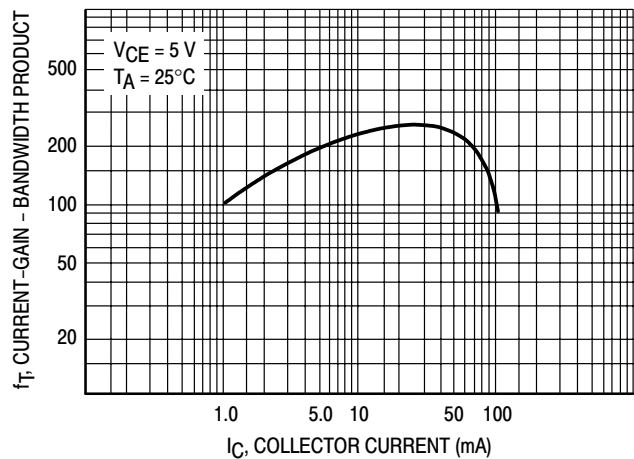
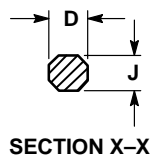
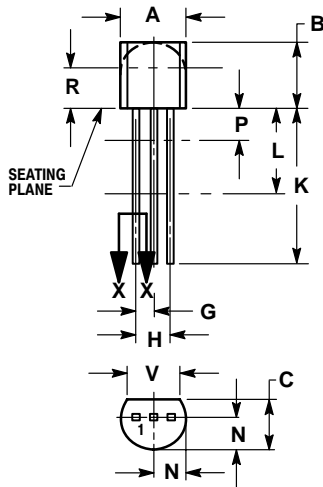


Figure 12. Current-Gain - Bandwidth Product

BC546 BC546B BC547A BC547B BC547C BC548B BC548C

PACKAGE DIMENSIONS

TO-92 (TO-226)
CASE 29-11
ISSUE AL




- NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: INCH.
 3. CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.
 4. LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.175	0.205	4.45	5.20
B	0.170	0.210	4.32	5.33
C	0.125	0.165	3.18	4.19
D	0.016	0.021	0.407	0.533
G	0.045	0.055	1.15	1.39
H	0.095	0.105	2.42	2.66
J	0.015	0.020	0.39	0.50
K	0.500	---	12.70	---
L	0.250	---	6.35	---
N	0.080	0.105	2.04	2.66
P	---	0.100	---	2.54
R	0.115	---	2.93	---
V	0.135	---	3.43	---

Notes

Notes

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